



Power Transistors

2N4036 2N4037 2N4314

40391 40394

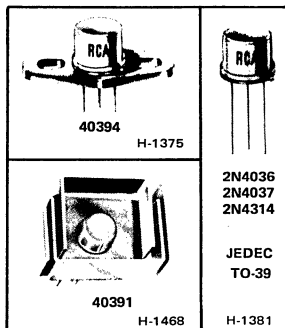
Medium-Power Silicon P-N-P Planar Transistors

General-Purpose Types for Industrial and Commercial Applications

Features:

- $\left. \begin{matrix} 2N4036 \\ 2N4037 \end{matrix} \right\}$ are p-n-p complements of $\left\{ \begin{matrix} 2N2102^{\Delta\Delta} \\ 2N3053 \end{matrix} \right.$
- Gain-bandwidth product (f_T) = 60 MHz min
- High breakdown voltages
- Maximum-area-of-operation curves
- Planar construction provides low noise and low leakage
- Low saturation voltages
- High pulsed beta at high collector current
- Fast switching (2N4036)

These devices are available with either 1½-inch leads (TO-5 package) or ½-inch leads (TO-39 package). The longer-lead versions are specified by suffix "L" after the type number; the shorter-lead versions are specified by suffix "S" after the type number.



The 2N4036, 2N4037, 2N4314[▲], 40391, and 40394 are double-diffused, epitaxial-planar, silicon p-n-p transistors; they differ in breakdown-voltage ratings, leakage-current, and saturation characteristics. The 40391 is a 2N4037 with a factory-attached heat radiator, intended for printed-circuit-board applications. Type 40394 is a 2N4037 with a factory-attached diamond-shaped mounting flange.

These transistors are intended for a wide variety of small-signal medium-power applications. With a minimum gain-

bandwidth product (f_T) of 60 MHz, these devices provide useful gain at high frequencies. In addition, the 2N4036 is useful in high-speed saturated switching applications.

[▲] Formerly Dev. Nos. TA2651, TA2670, and TA2670A, respectively.

^{▲▲} 2N2102 is a linear-beta type; the 2N3053 is a general-purpose type. For technical bulletins for these types, write to RCA Solid State Division, Box 3200, Somerville, N. J. 08876.

MAXIMUM RATINGS, Absolute Maximum Values:

MAXIMUM RATINGS, <i>Absolute Maximum Values:</i>		2N4036	2N4037 40391, 40394	2N4314	
* COLLECTOR-TO-BASE VOLTAGE	V_{CBO}	-90	-60	-90	V
COLLECTOR-TO-EMITTER SUSTAINING VOLTAGE:					
With 1.5 volts (V_{BE}) of reverse bias	$V_{CEV(sus)}$	-85	-60	-85	V
With external base-to-emitter resistance (R_{BE}) $\leq 200 \Omega$	$V_{CER(sus)}$	-85	-60	-85	V
With base open	$V_{CEO(sus)}$	-65	-40	-65	V
* EMITTER-TO-BASE VOLTAGE	V_{EBO}	-7	-7	-7	V
* COLLECTOR CURRENT	I_C	-1.0	-1.0	-1.0	A
* BASE CURRENT	I_B	-0.5	-0.5	-0.5	A
* TRANSISTOR DISSIPATION:	P_T				
At case temperatures up to 25°C		7	7(2N4037)	7	W
At free-air temperatures up to 25°C		—	7(40394)	—	W
At temperatures above 25°C		1	3.5(40391)	1	W
For pulsed operation		—	1(2N4037, 40394)	—	W
		See Figs. 6 and 7			
		See Fig. 1			
* TEMPERATURE RANGE:					
Storage & Operating (Junction)		-65 to 200			°C
* LEAD TEMPERATURE (During soldering):					
At distance $\geq 1/16$ in. (1.58 mm) from seating plane for 10 s max.		230			°C

* In accordance with JEDEC registration data format (JS-6 RDF-1 2N4036; JS-9 RDF-2 2N4037, 2N4314).

ELECTRICAL CHARACTERISTICS, at Case Temperature (T_C) = 25°C unless otherwise specified

CHARACTERISTIC	SYMBOL	TEST CONDITIONS					LIMITS						UNITS
		VOLTAGE V dc			CUR- RENT mA dc	2N4036		2N4037 40391 40394		2N4314			
		V _{CB}	V _{CE}	V _{BE}		I _C	Min.	Max.	Min.	Max.	Min.	Max.	
Collector Cutoff Current:	I _{CBO}	-90 -60				-	-0.1 ^a -0.02	-	-	-0.25 ^a	-	-0.25 ^a	mA μA
With emitter open	I _{CEO}		-30			-	-0.5 ^a	-	-5 ^a	-	-5 ^a	μA	
With base open	I _{CEX}		-85 -30	1.5 1.5		-	-100 ^a -0.1 ^a	-	-	-	-	-	mA
With base-emitter junction reverse biased T_C = 150°C													
Emitter Cutoff Current	I _{EBO}			7 5	0 0	-	-0.1 ^a -0.02	-	-1 ^a	-	-1 ^a	-	mA μA
Collector-to-Base Breakdown Voltage (I _E = 0)	V _{(BR)CBO}				-0.1	-90	-	-60 ^a	-	-90 ^a	-	V	
Emitter-to-Base Breakdown Voltage (I _E = -0.1mA)	V _{(BR)EBO}				0	-7	-	-7	-	-7	-	V	
Collector-to-Emitter Sustaining Voltage: (See Figs. 2 and 3) With base-emitter junction reverse biased	V _{CEV(sus)}			1.5	-100	-85 ^a	-	-60 ^a	-	-85 ^a	-	V	
With external base-to- emitter resistance (R _{BE}) ≤ 200 Ω	V _{CER(sus)}				-100	-85 ^a	-	-60 ^a	-	-85 ^a	-	V	
With base open	V _{CEO(sus)}				-100	-65 ^a	-	-40 ^a	-	-65 ^a	-	V	
Collector-to-Emitter Voltage (I _B = -15 mA)	V _{CE(sat)}				-150	-	-0.65	-	-1.4	-	-1.4	V	
Base-to-Emitter Voltage	V _{BE}		-10		-150	-	-1.1	-	-1.5 ^a	-	-1.5 ^a	V	
Base-to-Emitter Voltage (I _B = -15 mA)	V _{BE(sat)}				-150	-	-1.4	-	-	-	-	V	
DC Forward-Current Transfer Ratio	h _{FE}		-2 -10 -10 -10 -10		-150 -0.1 -1.0 -150 ^b -500 ^b	20 20 - 40 20	200 - - 140 -	- - 15 50 -	- - - 250 -	- - 15 50 -	- - - 250 -		
Common-Emitter, Small-Signal, Short-Circuit, Forward-Current Transfer Ratio (at f = 20 MHz)	h _{fe}		-10		-50	3.0	-	3.0	-	3.0	-		
Magnitude of Common-Emitter, Small-Signal, Short-Circuit, Forward-Current Transfer Ratio (at f = 20 MHz)	h _{fe}		-10		-50	3.0	-	3.0	10	3.0	10		
Collector-Base Capacitance (at f = 1 MHz, I _E = 0)	C _{cb}	-10				-	30	-	30 ^a	-	30 ^a	pF	
Input Capacitance	C _{ib}			0.5	0	-	90	-	90	-	90	pF	
Sat. Switching Time: C (See Figs. 10 and 11) Rise time Storage time Fall time Turn-on time Turn-off time	t _r t _s t _f t _{on} t _{off}	-30 -30 -30 -30 -30			-150 -150 -150 -150 -150	- - - - -	70 600 100 110 700	- - - - -	- - - - -	- - - - -	- - - - -	ns	
Thermal Resistance:													
Junction-to-Case	R _{θJC}					-	25 ^a	25 (max.) 2N4037 & 40394	-	-	25	°C/W	
Junction-to-Ambient	R _{θJA}					-	165	165 (max.) 2N4037 & 40394 50 (max.) 40391	-	-	165	°C/W °C/W	

^a CAUTION: The sustaining voltages $V_{CEV(sus)}$, $V_{CER(sus)}$, and $V_{CEO(sus)}$ MUST NOT be measured on a curve tracer.

These sustaining voltages should be measured by means of the test circuit shown in Fig. 2.

^b Pulsed; pulse duration $\leq 300 \mu\text{s}$, duty factor $< 2\%$.^c In accordance with JEDEC registration data format (US 6 DDF 1 2N4036; JS 9 DDF 2 2N4037, 2N4314).^d $I_{CB1} = I_{B2} = 15\text{ mA}$

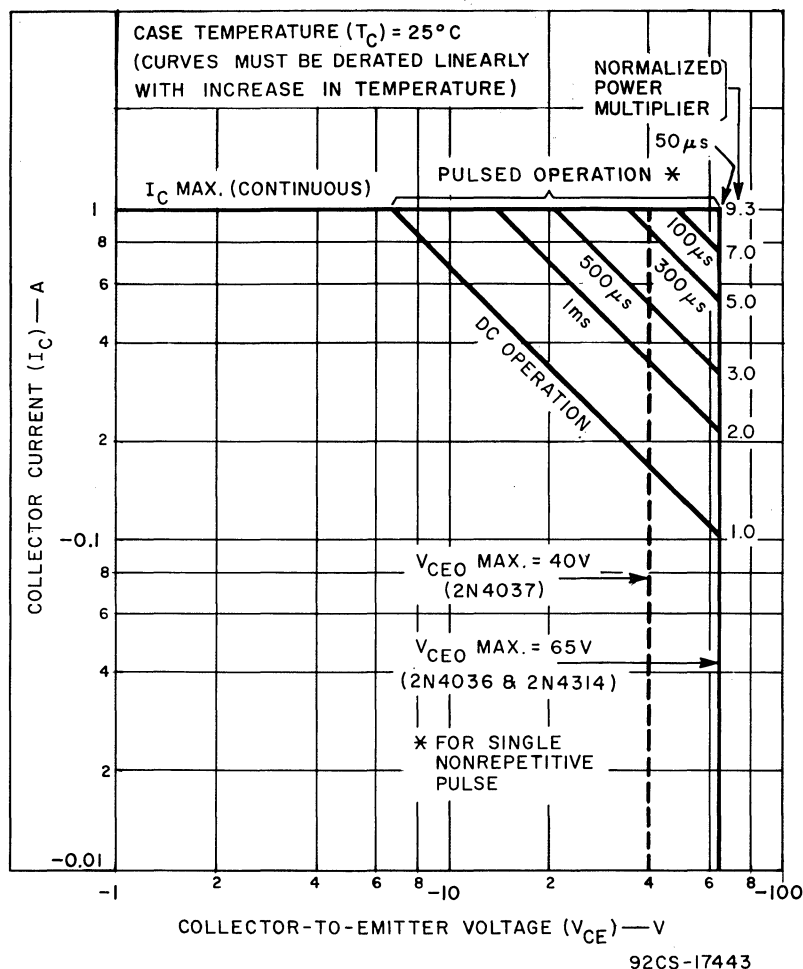


Fig. 1 — Maximum operating areas for types 2N4036, 2N4037, and 2N4314.

TERMINAL CONNECTIONS FOR 40394

Lead 1 — Emitter
Lead 2 — Base
Flange, Lead 3 — Collector

TERMINAL CONNECTIONS FOR 2N4036, 2N4037, 2N4314

Lead 1 — Emitter
Lead 2 — Base
Case, Lead 3 — Collector

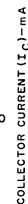
TERMINAL CONNECTIONS FOR 40391

Lead 1 — Emitter
Lead 2 — Base
Heat-Radiator, Lead 3 — Collector



92LS-1263

NOTE: The sustaining voltages $V_{CE0(sus)}$, $V_{CER(sus)}$, and $V_{CEV(sus)}$ are acceptable when the traces fall to the left and below point "A" for type 2N4036 and 2N4314, and point "B" for type 2N4037.



COLLECTOR-TO-EMITTER VOLTAGE (V_{CE}) = -10 V
FREQUENCY = 20 MHz
AMBIENT TEMPERATURE (T_A) = 25°C

Collector Current (I_C) [mA]	Small-Signal Forward Current Transfer Ratio (h_{fe})
-1	1.0
-2	2.0
-5	3.5
-10	5.2
-20	4.0
-50	2.5
-100	1.5

Fig.5 – Typical small-signal beta characteristic for all types.



Graph showing the percentage of rated current at specified voltage versus case temperature (T_c) in $^{\circ}\text{C}$. The current is constant at 100% until 25°C , then decreases linearly to 0% at 200°C . The line is labeled "DISSIPATION OR $T_{S/D}$ LIMITED".

Case Temperature (T_c) in $^{\circ}\text{C}$	Percentage of Rated Current at Specified Voltage
0	100
25	100
50	90
75	80
100	70
125	60
150	50
175	40
200	0

Fig.7 – Dissipation derating curve for types 2N4036, 2N4037, and 2N4314.

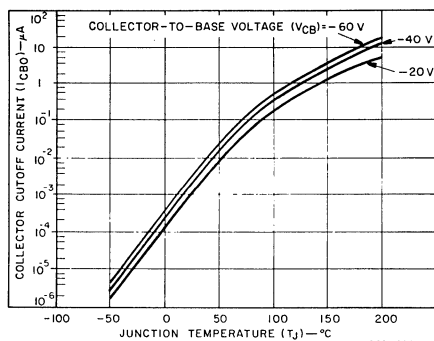


Fig. 8 — Typical collector-cutoff current vs. junction temperature for type 2N4036.

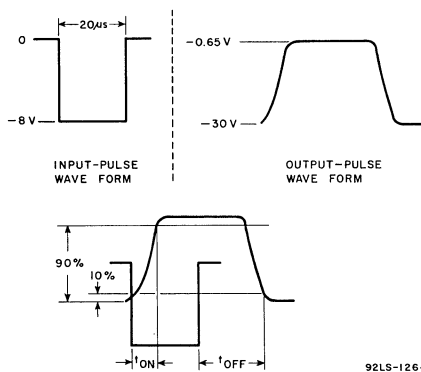


Fig. 10 — Oscilloscope display for measurement of switching times test circuit shown in Fig. 9.

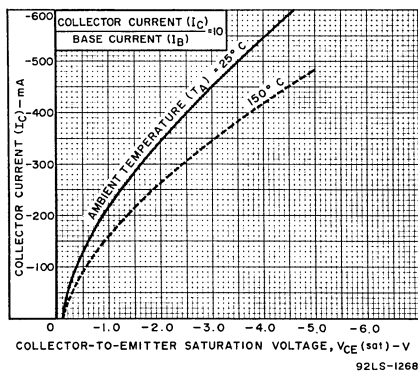


Fig. 12 — Typical saturation-voltage characteristics for type 2N4036.

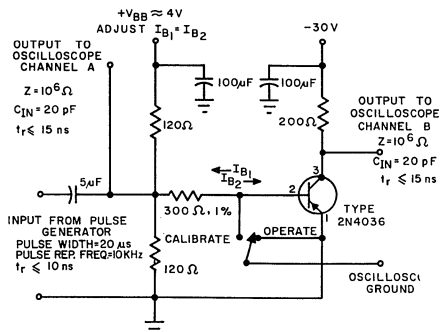


Fig. 9 — Circuit used to measure switching times for type 2N4036.

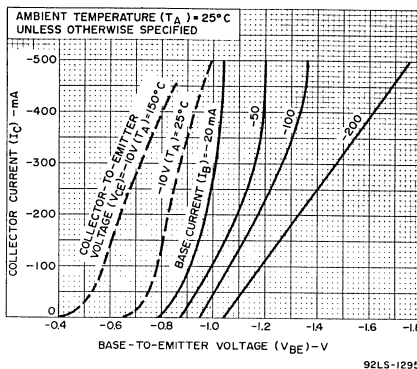


Fig. 11 — Typical transfer characteristics for types 2N4037 and 2N4314.

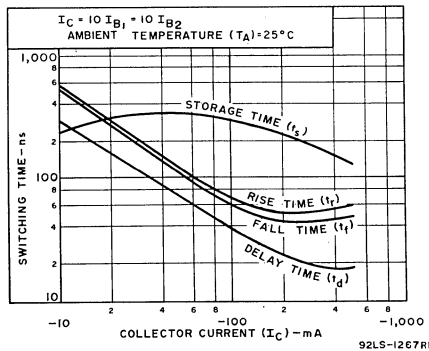


Fig. 13 — Typical saturated switching times for type 2N4036.

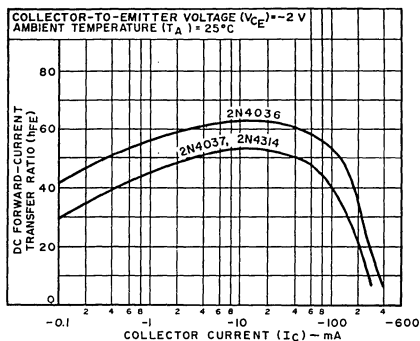


Fig. 14 - Typical dc beta characteristics for all types.

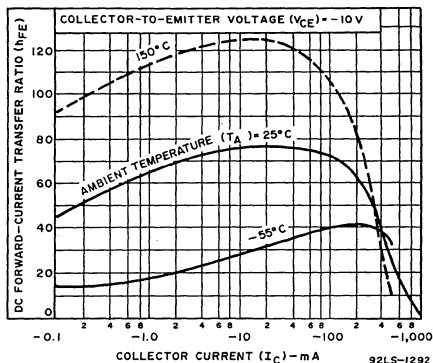


Fig. 15 - Typical dc beta characteristics for types 2N4037 and 2N4314.

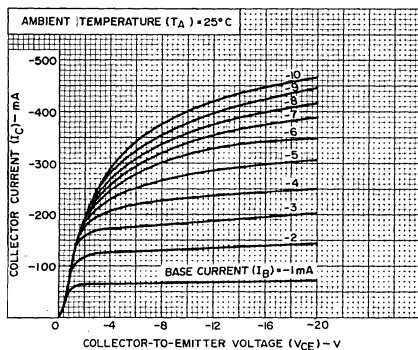


Fig. 16 - Typical output characteristics for types 2N4037 and 2N4314.

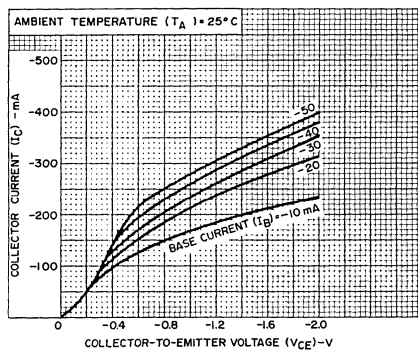


Fig. 17 - Typical output characteristics for types 2N4037 and 2N4314.

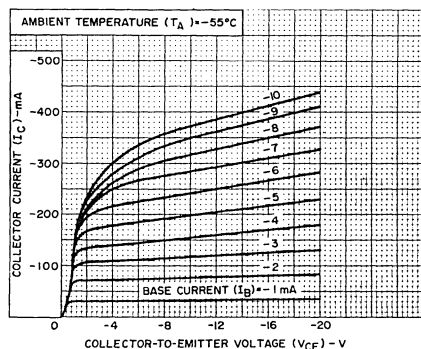


Fig. 18 - Typical output characteristics for types 2N4037 and 2N4314.

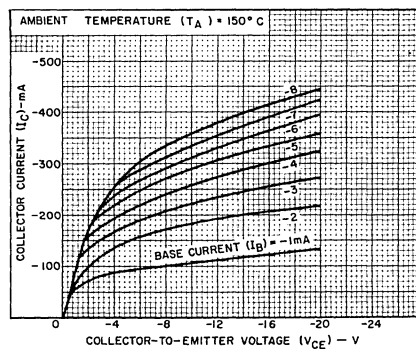


Fig. 19 - Typical output characteristics for types 2N4037 and 2N4314.